

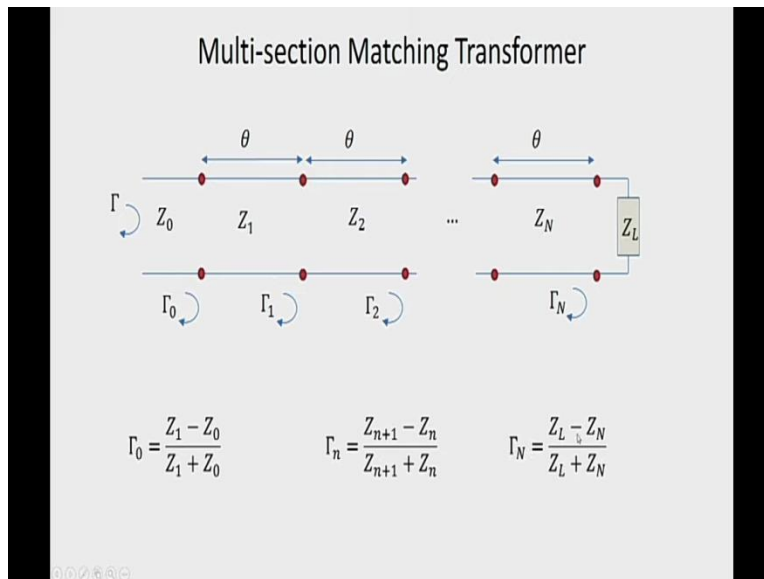
**Microwave Engineering**  
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**Lecture 13:**  
**Multi-section Matching Networks and Tapered Lines**

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$$\Gamma_0 = \frac{Z_1 - Z_0}{Z_1 + Z_0}$$

$$\Gamma_n = \frac{Z_{n+1} - Z_n}{Z_{n+1} + Z_n}$$

$$\Gamma_N = \frac{Z_L - Z_N}{Z_L + Z_N}$$



So we have seen the theory of small reflections, let us now consider a multi-section matching transformer. The figure shows a multi-section matching transformer where we have capital N number of sections, each section is having an electrical length theta and the transmission line sections have impedances  $Z_1$  and  $Z_2$  up to  $Z_n$ . And this transformer is designed to match this load  $Z_L$  to this transmission line having characteristic impedance  $Z_0$ . Now we introduce the partial reflection coefficients gamma zero, gamma one, gamma two, gamma n at these interfaces. So whenever there is a change in impedance and gamma is the overall reflection coefficient.

We can write gamma 0 equal to Z minus Z0 divided by Z1 plus Z0 and continuing in this manner. Gamma n is equal to Zn plus 1 minus Zn divided by Zn plus 1 plus Zn. And finally gamma capital N is Z1 minus Z capital N divided by Z1 plus Z capital N.

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Assume all  $Z_n$  increase or decrease monotonically across the transformer and  $Z_L$  is real.

$$\Gamma(\theta) = \Gamma_0 + \Gamma_1 e^{-j2\theta} + \Gamma_2 e^{-j4\theta} + \dots + \Gamma_N e^{-j2N\theta}$$

Further, on assuming the transformer to be symmetrical, we can write

$$\Gamma(\theta) = e^{-jN\theta} \{ \Gamma_0 [e^{jN\theta} + e^{-jN\theta}] + \Gamma_1 [e^{j(N-2)\theta} + e^{-j(N-2)\theta}] + \dots \}$$

**Multi-section Matching Transformer**

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Now we assume that all  $Z_n$  they increase or decrease monotonically and  $Z_1$  is real so that means this  $Z_1, Z_2, Z_n$  will increase either monotonically or decrease monotonically depending upon the values of  $Z_0$  and  $Z_L$ . If we consider the theory of small reflections what we have discussed, we can write gamma the overall reflection coefficient as a function of theta as gamma nought plus gamma 1. This is the partial reflection coefficient minus j, e to the power minus j2 theta plus gamma 2 e to the power minus j4 theta and gamma capital N e to the power minus j2 capital N theta. Further we assume that the transformer be symmetrical that means what we mean is gamma nought is equal to gamma N. Please note that, impedance increase or decrease monotonically.

But this impedance level for example  $Z_1$  and  $Z_0$  is selected in such a way that gamma nought becomes equal to gamma L which is decided by  $Z_L$  and  $Z_n$ . So if we assume this type of symmetry then we can write gamma theta e to the power minus jn theta gamma nought e to the power jn theta plus e to the power minus

$jn$  theta plus gamma 1 e to the power  $jn$  minus 2 theta plus e to the power minus  $jn$  minus 2 theta plus and so on.

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$$\Gamma(\theta) = e^{-jN\theta} \{ \Gamma_0 [e^{jN\theta} + e^{-jN\theta}] + \Gamma_1 [e^{j(N-2)\theta} + e^{-j(N-2)\theta}] + \dots \}$$

If  $N$  is even, the last term will be  $\Gamma_{N/2}$ .

If  $N$  is odd, the last term will be  $\Gamma_{(N-1)/2} (e^{j\theta} + e^{-j\theta})$ .

The above equation can also be written in terms of Fourier cosine series in  $\theta$  as:

$$\Gamma(\theta) = \begin{cases} 2e^{-jN\theta} \left[ \Gamma_0 \cos N\theta + \Gamma_1 \cos(N-2)\theta + \dots + \Gamma_n \cos(N-2n)\theta + \dots \right. \\ \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \left. + \frac{1}{2} \Gamma_{N/2} \right] \text{ for } N \text{ even} \\ 2e^{-jN\theta} \left[ \Gamma_0 \cos N\theta + \Gamma_1 \cos(N-2)\theta + \dots + \Gamma_n \cos(N-2n)\theta + \dots \right. \\ \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \qquad \left. + \Gamma_{(N-1)/2} \cos \theta \right] \text{ for } N \text{ odd} \end{cases}$$

**Multi-section Matching Transformer**

$$\Gamma(\theta) = e^{-jN\theta} \{ \Gamma_0 [e^{jN\theta} + e^{-jN\theta}] + \Gamma_1 [e^{j(N-2)\theta} + e^{-j(N-2)\theta}] + \dots \}$$

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Now capital  $N$  it can be even, in that case, the last term will be gamma capital  $N$  by 2. If capital  $N$  is odd the last term will be gamma capital  $n$  minus 1 by 2 e to the power  $j$  theta plus e to the power minus  $j$  theta. And these two equations can be written in terms of Fourier Cosine series. In theta s, gamma is a function of theta is equal to 2 e to the power minus  $jn$  theta, gamma nought cos  $n$  theta gamma 1 cos  $n$  minus 2 theta and finally half gamma  $n$  by 2 for an even and gamma as a function of theta equal to 2 e to the power minus  $j$  capital  $N$  theta gamma nought cos  $n$  theta plus gamma 1 cos  $n$  minus 2 theta and finally gamma  $n$  minus 1 by 2 cos theta when capital  $N$  is odd.

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The passband response of a binomial matching transformer for a given number of sections is as flat as possible near the design frequency.

Reflection coefficient of such a response is given by

$$\Gamma(\theta) = A(1 + e^{-j2\theta})^N$$

$$\therefore |\Gamma(\theta)| = |A(1 + e^{-j2\theta})^N| = |A| |e^{-j\theta}(e^{j\theta} + e^{-j\theta})|^N$$

$$|\Gamma(\theta)| = |A| |e^{-j\theta}|^N |(e^{j\theta} + e^{-j\theta})|^N = |A| |(2 \cos \theta)|^N$$

$$|\Gamma(\theta)| = 2^N |A| |\cos \theta|^N$$

$$|\Gamma(\theta)| = 0 \text{ for } \theta = \frac{\pi}{2} \text{ and } d^n |\Gamma(\theta)| / d\theta^n = 0 \text{ at } \theta = \frac{\pi}{2} \text{ for } n = 1, 2, \dots, (N - 1)$$

$$\theta = \beta l = \frac{\pi}{2} \text{ for } l = \lambda/4 \text{ at the design frequency } f_0$$

### Binomial Multi-section Matching Transformer

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$$|\Gamma(\theta)| = |A| |e^{-j\theta}|^N |(e^{j\theta} + e^{-j\theta})|^N = |A| |(2 \cos \theta)|^N$$

$$|\Gamma(\theta)| = 2^N |A| |\cos \theta|^N$$

$|\Gamma(\theta)| = 0$  for  $\theta = \frac{\pi}{2}$  and  $d^n |\Gamma(\theta)| / d\theta^n = 0$  at  $\theta = \frac{\pi}{2}$  for  $n = 1, 2, \dots, (N - 1)$

$\theta = \beta l = \frac{\pi}{2}$  for  $l = \lambda/4$  at the design frequency  $f_0$

So, now we have discussed how we can find out the reflection coefficient for a multi-section transformer in terms of the electrical length of the individual section theta and now let us see how we can design a Binomial multi-section matching transformer? Now the passband response of a binomial matching transformer for a given number of sections is as flat as possible near the design frequency. So that is why it is also called maximally flat response.

And in this type of design what we do the reflection coefficient that means gamma theta can be represented as gamma theta is equal to A 1 plus e to the power minus j2 theta raised to the power N. So we already have a Fourier expansion of gamma theta, so we are trying to now map this response so if we write modulus of

gamma theta then we can write its mod of  $A 2 \cos \theta$  mod raised to the power  $N$  and this can be written as modulus of gamma theta is equal to 2 to the power  $N$  modulus of  $A$  modulus of  $\cos \theta$  raised to the power  $N$ .

Now we can see that modulus of gamma theta equal to zero for theta equal to  $\pi/2$  and  $n$ th derivative of modulus gamma theta  $n$  is equal to zero at theta is equal to  $\pi/2$  for  $n$  equal to 1, 2 capital  $n$  minus 1. And we find that theta equal to  $\pi/2$  corresponds to  $l$  is equal to  $\lambda/4$  that means now we are considering a binomial multi-section transformer where each element, each transmission line sections are  $\lambda/4$  or quarter wave long at the design frequency.

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Letting  $f \rightarrow 0$  i.e.  $\theta = \beta l = 0$ , all sections are of zero electrical length.

$$\Gamma(\theta = 0) = 2^N A = \frac{Z_L - Z_0}{Z_L + Z_0}$$

Thus, the constant  $A$  can be determined as

$$A = 2^{-N} \frac{Z_L - Z_0}{Z_L + Z_0}$$

### Binomial Multi-section Matching Transformer

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Thus, the constant  $A$  can be determined as

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Now if you consider  $f$  equal to 0 then  $\theta$  becomes zero and all sections have zero electrical length. What does it mean that the line directly connected to the load impedance and therefore from the expression of  $\Gamma(\theta)$  evaluated at  $\theta$  equal to zero, we can write  $\Gamma$  to the power  $N$  and  $N$  is equal to  $Z_L$  minus  $Z_0$  divided by  $Z_L$  plus  $Z_0$  and the constant  $A$  can be determined as  $A$  is equal to  $\Gamma$  to the power  $N$  minus  $Z_L$  minus  $Z_0$  divided by  $Z_L$  plus  $Z_0$ . Please note that we have already mentioned that this matching transformer we are considering for a real load  $Z_L$ .

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On expanding  $\Gamma(\theta) = A(1 + e^{-j2\theta})^N$  using binomial expansion, we get

$$\Gamma(\theta) = A(1 + e^{-j2\theta})^N = A \sum_{n=0}^N C_n^N e^{-j2n\theta}$$

where,

$$C_n^N = \frac{N!}{(N-n)!n!}$$

On equating this response to the actual response, we get

$$\begin{aligned} \Gamma(\theta) &= A \sum_{n=0}^N C_n^N e^{-j2n\theta} = \Gamma_0 + \Gamma_1 e^{-j2\theta} + \Gamma_2 e^{-j4\theta} + \dots + \Gamma_N e^{-jN\theta} \\ &\Rightarrow AC_n^N = \Gamma_n \end{aligned}$$

### Binomial Multi-section Matching Transformer

On expanding  $\Gamma(\theta) = A(1 + e^{-j2\theta})^N$  using binomial expansion, we get

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Now we can expand this expression  $1 + e^{-j2\theta}$  to the power  $N$  using binomial expansion and we can write  $\Gamma(\theta)$  is equal to  $A$  sum of  $n$  equal to 0 to capital  $N$  and  $C_n^N e^{-j2n\theta}$  to the

power minus  $j2n\theta$ , where we are defining  $C_n^N$  as factorial  $N$  divided by factorial  $n$  and factorial  $N - n$ . And what we can do, as we said that now we equate it to the response of a multi section transformer which is given by  $\Gamma_n = \frac{Z_{n+1} - Z_n}{Z_{n+1} + Z_n}$ . And what we can do, we can equate on a term by term basis then we find  $C_n^N$  is equal to  $\frac{Z_{n+1} - Z_n}{2(Z_{n+1} + Z_n)}$ .

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Now

$$\Gamma_n = \frac{Z_{n+1} - Z_n}{Z_{n+1} + Z_n}$$

$\because \frac{Z_{n+1}}{Z_n} \approx 1$  and  $\ln x \approx 2 \frac{x-1}{x+1}$  for  $x$  close to unity,

$$\Gamma_n \approx \frac{1}{2} \ln \frac{Z_{n+1}}{Z_n}$$

$$\Rightarrow 2\Gamma_n = \ln \frac{Z_{n+1}}{Z_n}$$

$$\Rightarrow \ln \frac{Z_{n+1}}{Z_n} = 2AC_n^N = 2(2^{-N}) \frac{Z_L - Z_0}{Z_L + Z_0} C_n^N$$

$$\Rightarrow \ln \frac{Z_{n+1}}{Z_n} \approx 2^{-N} C_n^N \ln \frac{Z_L}{Z_0}$$

### Binomial Multi-section Matching Transformer

Now

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$$\Rightarrow \ln \frac{Z_{n+1}}{Z_n} \approx 2^{-N} C_n^N \ln \frac{Z_L}{Z_0}$$

Now we have  $\Gamma_n$  is  $Z_{n+1} - Z_n$  divided by  $Z_{n+1} + Z_n$ . What we can do as we have said that the change in characteristic impedance from one section to the next section is very small. So we can

use this equation  $\log$  of  $x$  is approximately equal to  $2x - 1$  divided by  $x + 1$  when  $x$  is close to unity. So our  $Z_n + 1$  by  $Z_n$  is close to unity, and using this expression for  $\log x$  we can write  $\Gamma_n$  to be equal to half  $\log Z_n + 1$  divided by  $Z_n$ . Therefore  $\log Z_n + 1$  by  $Z_n$  we can now substitute  $\Gamma_n$  which is  $2A C_n^N$  and then substitute the value of  $A$ , which is  $2$  to the power minus  $N$   $Z_1$  minus  $Z_0$  divided by  $Z_L + Z_0$  what we have derived earlier.

And then we can further simplify it into  $\log$  of  $Z_n + 1$  by  $Z_n$  is approximately  $2$  to the power minus  $N$ ,  $C_n^N \log Z_1$  by  $Z_0$ . Now this gives us a relationship where we can calculate  $Z_n$ ,  $Z_{small n}$  alternatively where we can calculate  $Z_{small n}$  recursively. So we start with  $Z_0$ , please note that right hand side is known so we can calculate  $Z_1$  then once  $Z_1$  is known we can calculate  $Z_2$  and in that way we can keep calculating till  $Z_{capital N}$ . We can find the characteristic impedance of all the  $\lambda/4$  sections that are used in that multi-section transformer design.

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Let  $\Gamma_m$  be the maximum value of the reflection coefficient that can tolerated over the passband

$$\Gamma_m = 2^N |A| \cos^N \theta_m \quad \Rightarrow \theta_m = \cos^{-1} \left[ \frac{1}{2} \left( \frac{\Gamma_m}{|A|} \right)^{1/N} \right]$$

where  $\theta_m < \frac{\pi}{2}$ , is the lower edge of the passband.

Therefore, the fractional bandwidth can be obtained as

$$\frac{\Delta f}{f_0} = \frac{2(f_0 - f_m)}{f_0} = 2 - \frac{4\theta_m}{\pi} = 2 - \frac{4}{\pi} \cos^{-1} \left[ \frac{1}{2} \left( \frac{\Gamma_m}{|A|} \right)^{1/N} \right]$$

### Binomial Multi-section Matching Transformer

Let  $\Gamma_m$  be the maximum value of the reflection coefficient that can tolerated over the passband

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We can also have an estimate of the bandwidth that we can have for this type of a multi-section quarter-wave matching transformer. Let  $\Gamma_m$  be the maximum reflection coefficient that we can tolerate over the passband then we can write  $\Gamma_m$  is equal to  $\frac{2}{A} \cos \theta_m$  raised to the power  $N$  and from there we can find out  $\theta_m$  corresponding to that value of  $\Gamma_m$ , and we know that the reflection coefficient will increase on either side of the design frequency for which we have  $\theta$  is equal to  $\frac{\pi}{2}$ .

So we take this  $\theta_m$  value less than  $\frac{\pi}{2}$  and now we can write fractional bandwidth  $\frac{\Delta f}{f_0}$  is equal to  $\frac{2}{f_0} \frac{f_m - f_0}{f_0}$  divided by  $f_0$ ,  $f_m$  is that frequency at which the reflection coefficient becomes  $\Gamma_m$  and that can be written as  $\frac{2}{\pi} \cos^{-1} \frac{\Gamma_m}{A}$  divided by modulus of  $A$  raised to the power  $\frac{1}{N}$ . Here this  $N$  is the number of sections that are present in the transformer.

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Let the impedance  $Z$  of the line varies with  $z$  as shown

Let the tapered line being made up of incremental line lengths  $\Delta z$  as shown.

$$\Delta \Gamma = \frac{Z + \Delta Z - Z}{Z + \Delta Z + Z} \approx \frac{\Delta Z}{2Z}$$

For  $\Delta z \rightarrow 0$ ,

$$d\Gamma = \frac{dZ}{2Z} = \frac{1}{2} \frac{d(\ln(Z/Z_0))}{dz} dz$$

Note that:  $\frac{d(\ln(Z/Z_0))}{dz} dz = \frac{Z_0}{Z} \frac{1}{Z_0} \frac{dZ}{dz} dz = \frac{dZ}{Z}$

## Impedance matching with Tapered lines

Let the impedance  $Z$  of the line varies with  $z$  as shown

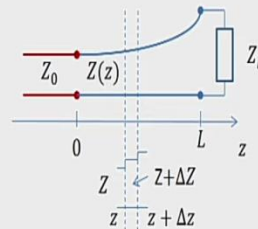
Let the tapered line being made up of incremental line lengths  $\Delta z$  as shown.

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For  $\Delta z \rightarrow 0$ ,

$$d\Gamma = \frac{dZ}{2Z} = \frac{1}{2} \frac{d(\ln(Z/Z_0))}{dz} dz$$

Note that:  $\frac{d(\ln(Z/Z_0))}{dz} = \frac{1}{Z} \frac{dZ}{dz} = \frac{dZ}{Z dz}$



$Z_L$  is considered to be a resistive load

Let us now move onto another method of impedance matching, the impedance matching with tapered lines. Here the impedance capital  $Z$  of the line varies with distance  $z$  and we are showing this in this figure. So at small  $z$  is equal to zero we have capital  $Z$ ,  $Z$  is equal to  $Z_0$  and over a length  $L$  this impedance capital  $Z$  changes to  $Z_L$ . Now what we can do, we can consider this tapered line being made up of incremental line lengths  $\Delta z$  as shown.

So here you can see we have an incremental length  $\Delta z$ , on the left-hand side we have impedance capital  $Z$  and over this length small  $\Delta z$  we assume the impedance to be capital  $Z$  plus  $\Delta Z$  and therefore at this interface the reflection coefficient the partial reflection coefficient  $\Delta\Gamma$  can be written as  $Z + \Delta Z - Z$  divided by  $Z + \Delta Z + Z$ . Now in the denominator we neglect this  $\Delta Z$  term and we can write the approximate expression as  $\Delta Z$  by  $2Z$ . Now when this  $\Delta z$  tends to zero this length tends to zero, we can write  $\Delta\Gamma$  as  $d\Gamma$ .

So  $d\Gamma$  becomes equal to  $d$  of capital  $Z$  divided by  $2Z$  and this can be written in this form  $\frac{1}{2} \frac{d(\ln(Z/Z_0))}{dz} dz$ . This can be seen from here because  $d$  of  $\ln(Z/Z_0)$  by  $Z_0$  by  $dz$  into  $dz$  is essentially  $d$  of capital  $Z$  by capital  $Z$ .

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$$d\Gamma = \frac{dZ}{2Z} = \frac{1}{2} \frac{d(\ln(Z/Z_0))}{dz} dz$$

By theory of small reflection, the total reflection coefficient at  $z = 0$  is given by

$$\Gamma = \frac{1}{2} \int_0^L e^{-2j\beta z} \frac{d(\ln(Z/Z_0))}{dz} dz$$

For a given  $Z(z)$  we can find  $\Gamma$

Impedance matching with Tapered lines

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Next what we do, now we have this expression we apply again the theory of small reflection. Now the total reflection coefficient at  $Z$  is equal to zero. That means at the input of the tapered line is given by gamma is equal to half integration 0 to L, e to the power minus 2j beta z, this is the phase shift and d of log of capital Z by  $Z_0$  by dz into dz. Now this gives the overall reflection coefficient at the input of the tapered line. Please note that if we know  $Z(z)$  that means the impedance variation as a function of distance  $Z$  we can find gamma.

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$$Z(z) = Z_0 e^{\alpha z} \text{ for } 0 \leq z \leq L$$

$$\text{Since } Z(z = L) = Z_L = Z_0 e^{\alpha L}, \text{ therefore, } \alpha = \frac{1}{L} \ln \frac{Z_L}{Z_0}$$

$$\text{We have seen } \Gamma = \frac{1}{2} \int_0^L e^{-2j\beta z} \frac{d(\ln(Z/Z_0))}{dz} dz$$

$$\text{Therefore, } \Gamma = \frac{1}{2} \int_0^L e^{-2j\beta z} \frac{d(\ln(e^{\alpha z}))}{dz} dz = \frac{1}{2} \alpha \int_0^L e^{-2j\beta z} dz$$

$$\Gamma = \frac{1}{2L} \ln \frac{Z_L}{Z_0} \int_0^L e^{-2j\beta z} dz = \frac{1}{2} \ln \frac{Z_L}{Z_0} e^{-j\beta L} \frac{\sin \beta L}{\beta L}$$

**Exponential Taper**

$Z(z) = Z_0 e^{\alpha z}$  for  $0 \leq z \leq L$

Since  $Z(z = L) = Z_L = Z_0 e^{\alpha L}$ , therefore,  $\alpha = \frac{1}{L} \ln \frac{Z_L}{Z_0}$

We have seen  $\Gamma = \frac{1}{2} \int_0^L e^{-2j\beta z} \frac{d(\ln(Z/Z_0))}{dz} dz$

Therefore,  $\Gamma = \frac{1}{2} \int_0^L e^{-2j\beta z} \frac{d(\ln(e^{\alpha z}))}{dz} dz = \frac{1}{2} \alpha \int_0^L e^{-2j\beta z} dz$

$$\Gamma = \frac{1}{2L} \ln \frac{Z_L}{Z_0} \int_0^L e^{-2j\beta z} dz = \frac{1}{2} \ln \frac{Z_L}{Z_0} e^{-j\beta L} \frac{\sin \beta L}{\beta L}$$

So let us see how we can do that, so we consider a very commonly used taper which is an exponential taper. Here capital Z as a function of distance Z is given by  $Z_0 e$  to the power alpha z, for zero less than z and Z less than capital L. Now since this capital Z at z is equal to L is  $Z_L$  and therefore we can find alpha to be equal to 1 by L log of  $Z_L$  by  $Z_0$ . And we have the expression for gamma, now in this expression we have we can now substitute Z equal to  $Z_0 e$  to the power alpha z so this  $Z_0$  and this  $Z_0$  will get canceled, we will be left with log of e to the power alpha z and this can be log of e to the power alpha Z will give alpha z.

When differentiated we will be left with alpha and integration of 0 to capital L e to the power minus 2 j beta z dz. Now we substitute the expression for alpha from 1 by L log of capital  $Z_L$  by  $Z_0$  and then carry out this integration, then we get the final expression for the reflection coefficient gamma to be half log of  $Z_L$  by  $Z_0 e$  to the power minus j beta L sine beta L by beta L.

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$$\Gamma = \frac{1}{2} \ln \frac{Z_L}{Z_0} e^{-j\beta L} \frac{\sin \beta L}{\beta L}$$

It may be noted that here  $\beta$  is assumed to be not a function of z.

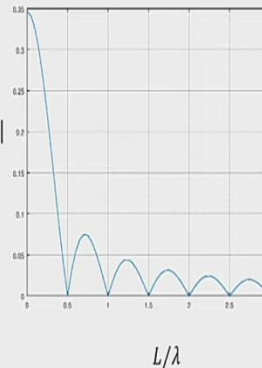
Peak values of  $|\Gamma|$  decreases with L and the length should greater than  $\lambda/2$  to minimize mismatch at low frequency

## Exponential Taper

$$\Gamma = \frac{1}{2} \ln \frac{Z_L}{Z_0} e^{-j\beta L} \frac{\sin \beta L}{\beta L}$$

It may be noted that here  $\beta$  is assumed to be **not** a function of  $z$ .

Peak values of  $|\Gamma|$  decreases with  $L$  and the length should be greater than  $\lambda/2$  to minimize mismatch at low frequency.



The magnitude of the reflection coefficient is plotted in this figure as a function of  $L$  by  $\lambda$ , and we can see that as  $L$  by  $\lambda$  increases the peak value of  $\text{mod } \gamma$  decreases, and the length should be greater than  $\lambda$  by 2, at least  $\lambda$  by two to minimize mismatch at low frequency. This is because this exponential taper is designed to operate for broadband of frequencies and we want the reflection coefficient to be less than some specified value, say if it is to be less than 0.1 even at the lowest operating frequency then we should have  $L$  by  $\lambda$  at that frequency greater than 0.5.

So, the peak values of  $\text{mod } \gamma$  decrease with  $L$  and length should be greater than  $\lambda$  by 2 to minimize mismatch at low frequency, and it is to be noted that we have considered  $\beta$  independent of  $z$  that means it is not a function of  $z$  and such assumptions are valid for TEM lines. There are other forms of tapers like triangular tapers, and the impedance matching can be performed with such tapers. This actually brings to the end of this module.

In this module we have discussed in detail some of the impedance matching techniques starting with the  $\lambda$  elements then we have seen matching with stubs. We have seen how impedance matching can be done using a quarter-wave transformer, we have seen how we can design a multi-section quarter-wave transformer, and finally we have seen how we can use taper line for doing impedance matching. Our next module will be on microwave resonators where we will study first series and parallel resonant circuits, and we will have discussion on  $Q$  factor bandwidth, and then we will discuss transmission line resonators as well as waveguide resonators.